

Product data sheet

1. Product profile

1.1 General description

Single high-speed switching diode, fabricated in planar technology, and encapsulated in a small hermetically sealed glass SOD80C Surface-Mounted Device (SMD) package.

1.2 Features and benefits

High switching speed: t_{rr} ≤ 4 ns

Reverse voltage: V_R ≤ 75 V

Repetitive peak reverse voltage: V_{RRM} ≤ 100 V
 Repetitive peak forward current: I_{FRM} ≤ 450 mA

Small hermetically sealed glass SMD package

1.3 Applications

- High-speed switching
- Reverse polarity protection

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		<u>[1]</u> -	-	200	mA
I _{FRM}	repetitive peak forward current		-	-	450	mA
V_R	reverse voltage		-	-	75	V
V _F	forward voltage	$I_F = 100 \text{ mA}$	-	-	1000	mV
t _{rr}	reverse recovery time		[2] _	-	4	ns

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



^[2] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

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2. Pinning information

Table 2. Pinning

	3		
Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	
2	anode	k	1 2 006aab040

^[1] The marking band indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAS32L	-	hermetically sealed glass surface-mounted package; 2 connectors	SOD80C

4. Marking

Table 4. Marking codes

Type number	Marking code
BAS32L	marking band

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	75	V
I _F	forward current		<u>[1]</u> -	200	mA
I _{FRM}	repetitive peak forward current		-	450	mA
I _{FSM} non-repetitive current	non-repetitive peak forward	square wave	[2]		
	current	t _p = 1 μs	-	4	Α
		$t_p = 1 \text{ ms}$	-	1	Α
		t _p = 1 s	-	0.5	Α

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 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	$T_{amb} = 25 ^{\circ}C$	<u>[1]</u> -	500	mW
Tj	junction temperature		-	200	°C
T _{amb}	ambient temperature		-65	+200	°C
T _{stg}	storage temperature		-65	+200	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	350	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	300	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

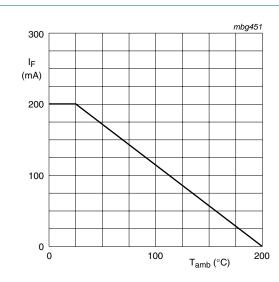
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 5 \text{ mA}$	620	-	750	mV
		I _F = 100 mA	-	-	1000	mV
		$I_F = 100 \text{ mA}; T_j = 100 ^{\circ}\text{C}$	-	-	930	mV
I _R reverse current		V _R = 20 V	-	-	25	nA
	V _R = 75 V	-	-	5	μΑ	
		V _R = 20 V; T _j = 150 °C	-	-	50	μΑ
		V _R = 75 V; T _j = 150 °C	-	-	100	μΑ
C _d	diode capacitance	$V_R = 0 V; f = 1 MHz$	-	-	2	pF
t _{rr}	reverse recovery time		[1] -	-	4	ns
V_{FR}	forward recovery voltage		[2] _	-	2.5	V

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

^[2] $T_i = 25$ °C prior to surge.

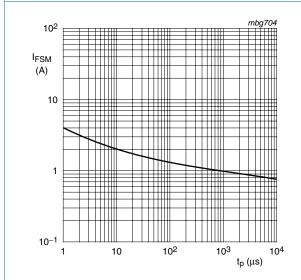
^[2] When switched from I_F = 50 mA; t_r = 20 ns.

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FR4 PCB, standard footprint

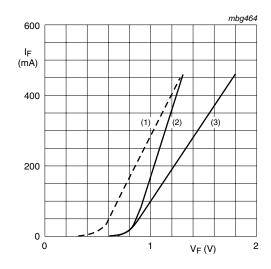
Fig 1. Forward current as a function of ambient temperature; derating curve



Based on square wave currents.

T_i = 25 °C prior to surge

Fig 3. Non-repetitive peak forward current as a function of pulse duration; maximum values

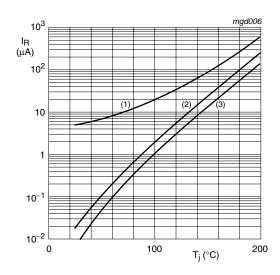


(1) $T_j = 175$ °C; typical values

(2) $T_j = 25 \,^{\circ}C$; typical values

(3) $T_i = 25 \,^{\circ}C$; maximum values

Fig 2. Forward current as a function of forward voltage



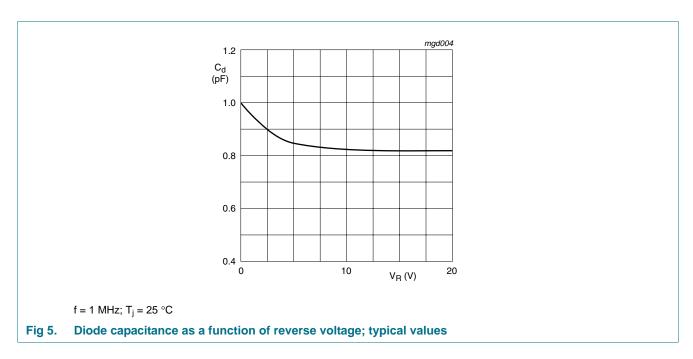
(1) $V_R = 75 \text{ V}$; maximum values

(2) V_R = 75 V; typical values

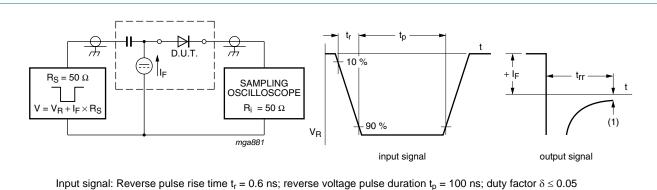
(3) $V_R = 20 \text{ V}$; typical values

Fig 4. Reverse current as a function of junction temperature

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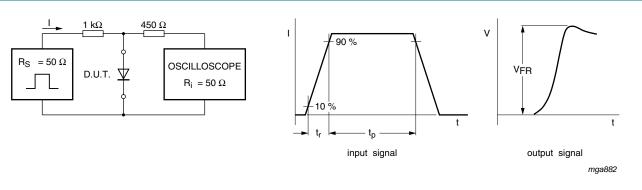
8. Test information



Input signal: Reverse pulse rise time t_r = 0.6 ns; reverse voltage pulse duration t_p = 100 ns; duty factor $\delta \le$ 0.05 Oscilloscope: Rise time t_r = 0.35 ns

(1) $I_R = 1 \text{ mA}$

Fig 6. Reverse recovery time test circuit and waveforms



Input signal: Forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty factor $\delta \le 0.005$

Fig 7. Forward recovery voltage test circuit and waveforms

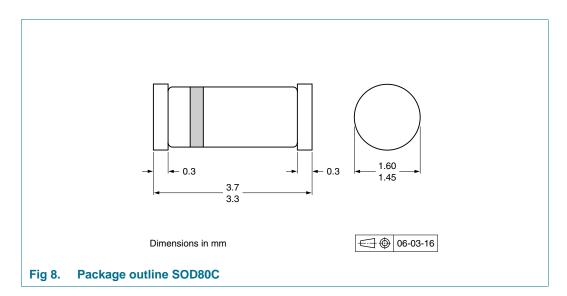
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9. Package outline



10. Packing information

Table 8. Packing methods

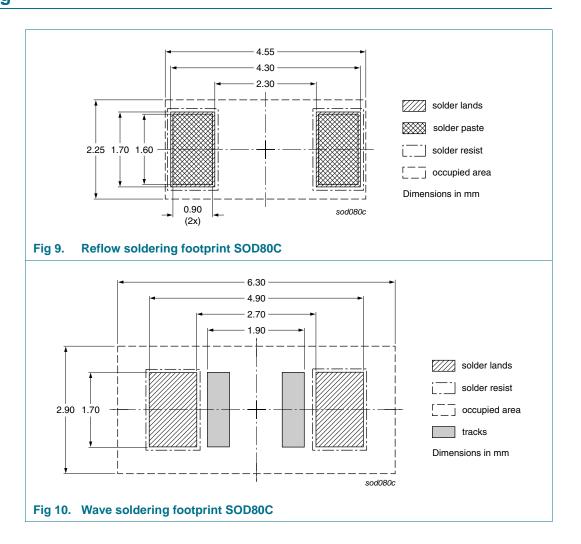
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			2500	10000
BAS32L	SOD80C	4 mm pitch, 8 mm tape and reel	-115	-135

^[1] For further information and the availability of packing methods, see Section 14.

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11. Soldering



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12. Revision history

Table 9. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS32L v.7	20110120	Product data sheet	-	BAS32L v.6
Modifications:	• Table 4 "Mar	king codes": amended		
	 Section 13 "L 	<u>egal information"</u> : updated		
BAS32L v.6	20081029	Product data sheet	-	BAS32L v.5
BAS32L v.5	20080103	Product data sheet	-	BAS32L v.4
BAS32L v.4	20050322	Product data sheet	-	BAS32L v.3
BAS32L v.3	20020123	Product specification	-	BAS32L v.2
BAS32L v.2	19960910	Product specification	-	BAS32L v.1
BAS32L v.1	19960423	Product specification	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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